DATASHEET

Description

The 9DBU0231 is a member of IDT's 1.5V Ultra-Low-Power (ULP) PCle family. The device has 2 output enables for clock management.

Recommended Application

1.5V PCle Gen1-2-3 Zero-Delay/Fan-out Buffer (ZDB/FOB)

Output Features

• 2 - 1-167MHz Low-Power (LP) HCSL DIF pairs

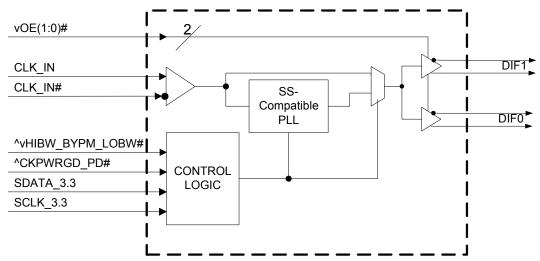
Key Specifications

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew <50ps
- DIF phase jitter is PCle Gen1-2-3 compliant
- DIF additive phase jitter is <100fs rms for PCle Gen3
- DIF additive phase jitter <350fs rms for 12k-20MHz

Features/Benefits

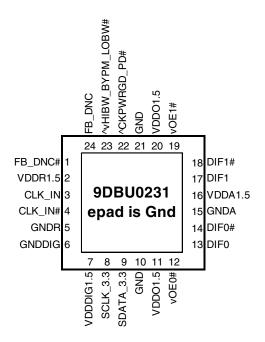
- LP-HCSL outputs; save 4 resistors compared to standard HCSL outputs
- 35mW typical power consumption in PLL mode; eliminates thermal concerns
- Spread Spectrum (SS) compatible; allows SS for EMI reduction
- OE# pins; support DIF power management
- HCSL compatible differential input; can be driven by common clock sources
- SMBus-selectable features; optimize signal integrity to application
 - slew rate for each output
 - differential output amplitude
- Pin/SMBus selectable PLL bandwidth and PLL Bypass; optimize PLL to application
- Outputs blocked until PLL is locked; clean system start-up
- Device contains default configuration; SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 24-pin 4x4mm VFQFPN; minimal board space

Block Diagram





Pin Configuration



24-pin VFQFPN, 4x4 mm, 0.5mm pitch

^ prefix indicates internal 120KOhm pull up resistor ^v prefix indicates internal 120KOhm pull up AND pull down resistor (biased to VDD/2) v prefix indicates internal 120KOhm pull down resistor

SMBus Address Selection Table

Address	+ Read/Write bit
1101101	х

Power Management Table

CKPWRGD PD#	CLK_IN	SMBus OEx# Pin		DIF	PLL	
CKFWKGD_FD#	CLK_IN	OEx bit	OLX# FIII	True O/P	Comp. O/P	FLL
0	Х	Х	Х	Low	Low	Off
1	Running	0	Х	Low	Low	On ¹
1	Running	1	0	Running	Running	On ¹
1	Running	1	1	Low	Low	On ¹

^{1.} If Bypass mode is selected, the PLL will be off, and outputs will be running.

Power Connections

Pin Numb	er	Description
VDD	GND	Description
2	5	Input receiver analog
7	6	Digital Power
11,20	10,21	DIF outputs
16	15	PLL Analog

Note: epad on this device is not electrically connected to the die. It should be connected to ground for best thermal performance.

PLL Operating Mode

		Byte1 [7:6]	Byte1 [4:3]
HiBW_BypM_LoBW#	MODE	Readback	Control
0	PLL Lo BW	00	00
М	Bypass	01	01
1	PLL Hi BW	11	11



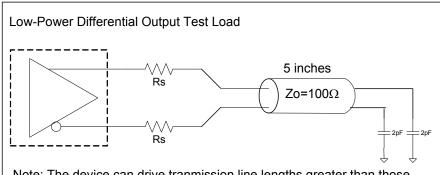
Pin Descriptions

Pin#	Pin Name	Pin Type	Description
			Complement clock of differential feedback. The feedback output
1	FB_DNC#	DNC	and feedback input are connected internally on this pin. Do not
			connect anything to this pin.
2	VDDR1.5	PWR	1.5V power for differential input clock (receiver). This VDD should
	VDDN1.5	FVVN	be treated as an Analog power rail and filtered appropriately.
3	CLK_IN	IN	True Input for differential reference clock.
4	CLK_IN#	IN	Complementary Input for differential reference clock.
5	GNDR	GND	Analog Ground pin for the differential input (receiver)
6	GNDDIG	GND	Ground pin for digital circuitry
7	VDDDIG1.5	PWR	1.5V digital power (dirty power)
8	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
9	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
10	GND	GND	Ground pin.
11	VDDO1.5	PWR	Power supply for outputs, nominally 1.5V.
			Active low input for enabling DIF pair 0. This pin has an internal pull-
12	vOE0#	IN	down.
			1 =disable outputs, 0 = enable outputs
13	DIF0	OUT	Differential true clock output
14	DIF0#	OUT	Differential Complementary clock output
15	GNDA	GND	Ground pin for the PLL core.
16	VDDA1.5	PWR	1.5V power for the PLL core.
17	DIF1	OUT	Differential true clock output
18	DIF1#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 1. This pin has an internal pull-
19	vOE1#	IN	down.
			1 =disable outputs, 0 = enable outputs
20	VDDO1.5	PWR	Power supply for outputs, nominally 1.5V.
21	GND	GND	Ground pin.
			Input notifies device to sample latched inputs and start up on first
22	^CKPWRGD_PD#	IN	high assertion. Low enters Power Down Mode, subsequent high
	TOKI WIND_I D#	111	assertions exit Power Down Mode. This pin has internal pull-up
			resistor.
23	^vHIBW_BYPM_LOBW#	LATCHED	Trilevel input to select High BW, Bypass or Low BW mode.
23		IN	See PLL Operating Mode Table for Details.
			True clock of differential feedback. The feedback output and
24	FB_DNC	DNC	feedback input are connected internally on this pin. Do not connect
			anything to this pin.
25	ePad	GND	Connect epad to ground.

NOTE: DNC indicates Do Not Connect anything to this pin.



Test Loads

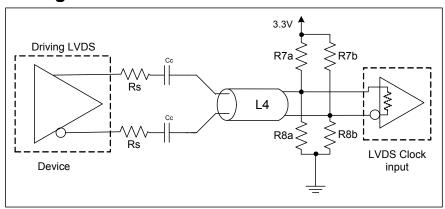


Note: The device can drive tranmission line lengths greater than those allowed by the PCle SIG.

Alternate Differential Output Terminations

Rs	Zo	Units
33	100	Ohms
27	85	Offilis

Driving LVDS



Driving LVDS inputs

Briving Ev Bo inputo							
	,						
	Receiver has Receiver does not						
Component	termination	have termination	Note				
R7a, R7b	10K ohm	140 ohm					
R8a, R8b	5.6K ohm	75 ohm					
Cc	0.1 uF	0.1 uF					
Vcm	1.2 volts	1.2 volts					



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBU0231. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx		-0.5		2	V	1,2
Input Voltage	V_{IN}		-0.5		V _{DD} +0.5	V	1,3
Input High Voltage, SMBus	V_{IHSMB}	SMBus clock and data pins			3.3	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Clock Input Parameters

TA = T_{AMR}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

The Tamb, Supply Voltages per hermal operation conditions, See Test Leads for Leading Conditions								
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES	
Input Common Mode Voltage - DIF_IN	V _{COM}	Common Mode Input Voltage	200		725	mV	1	
Input Swing - DIF_IN	V _{SWING}	Differential value	300		1450	mV	1	
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2	
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA		
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45	50	55	%	1	
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		150	ps	1	

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.0V.

² Slew rate measured through +/-75mV window centered around differential zero



Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

TA = TAMB, Supply Voltages		operation conditions, See Test Loads for Loading Cor	uitions				Ī
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.425	1.5	1.575	V	
Ambient Operating	T_{AMB}	Commmercial range	0	25	70	°C	1
Temperature	' AMB	Industrial range	-40	25	85	°C	1
Input High Voltage	V_{IH}	Single-ended inputs, except SMBus	0.75 V _{DD}		$V_{DD} + 0.3$	V	
Input Mid Voltage	V_{IM}	Single-ended tri-level inputs ('_tri' suffix)	$0.4~V_{DD}$		0.6 V _{DD}	V	
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus	-0.3		0.25 V _{DD}	V	
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Innut Cument		Single-ended inputs					
Input Current	I _{INP}	$V_{IN} = 0 \text{ V}$; Inputs with internal pull-up resistors	-200		200	uA	
		V _{IN} = VDD; Inputs with internal pull-down resistors					
Innut Francisco	F _{ibyp}	Bypass mode	1		167	MHz	2
Input Frequency	F _{ipII}	100MHz PLL mode	20	100.00	110	MHz	2
Pin Inductance	L _{pin}				7	nH	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,5
	C _{OUT}	Output pin capacitance			6	pF	1
Oll Orabili aria	T _{STAB}	From V _{DD} Power-Up and after input clock					4.0
Clk Stabilization		stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation	ŧ	Allowable Frequency for PCIe Applications	30		33	kHz	
Frequency PCIe	f _{MODINPCle}	(Triangular Modulation)	30		33	KΠZ	
Input SS Modulation	f _{MODIN}	Allowable Frequency for non-PCIe Applications	0		66	kHz	
Frequency non-PCIe	IMODIN	(Triangular Modulation)	Ů		00	KIIZ	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion	1		3	clocks	1,3
	LATOL#	DIF stop after OE# deassertion			_		, -
Tdrive_PD#	t _{DRVPD}	DIF output enable after			300	us	1,3
Tfall		PD# de-assertion					
	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	V _{ILSMB}				0.6	V	
SMBus Input High Voltage	V _{IHSMB}	$V_{DDSMB} = 3.3V$, see note 4 for $V_{DDSMB} < 3.3V$	2.1		3.3	V	4
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	_
Nominal Bus Voltage	$V_{\rm DDSMB}$	Bus Voltage	1.425		3.3	V	ļ
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	6
Frequency	- INIAVOINID						

¹Guaranteed by design and characterization, not 100% tested in production.

 $^{^2\}mbox{Control}$ input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

 $^{^{4}}$ For V_{DDSMB} < 3.3V, V_{IHSMB} >= 0.8x V_{DDSMB}

⁵DIF_IN input

⁶The differential input clock must be running for the SMBus to be active



Electrical Characteristics-DIF Low-Power HCSL Outputs

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

	·	, , , , , , , , , , , , , , , , , , ,					
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting (100MHz)	1.4	2.4	3.5	V/ns	1,2,3
Siew rate	dV/dt	Scope averaging on, slow setting (100MHz)	0.9	1.7	2.5	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		2.7	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	630	735	850	mV	7
Voltage Low	V_{LOW}	averaging on)	-150	-16	150	1111	7
Max Voltage	Vmax	Measurement on single ended signal using		779	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off) -300 -45			IIIV	7	
Vswing	Vswing	Scope averaging off	300	1503		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	405	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		12	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Current Consumption

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DDR}	VDDR @100MHz		3	6	mA	1
	I _{DDDIG}	VDDIG, All outputs @100MHz		0.125	0.25	mA	1
	I _{DDAO}	VDDA+VDDO, PLL Mode, All outputs @100MHz		13	17	mA	1
	I _{DDRPD}	VDDR, CKPWRGD_PD# = 0		0.1	0.3	mA	1,2,3
Powerdown Current	I _{DDDIGPD}	VDDDIG, CKPWRGD_PD# = 0		0.1	0.2	mA	1,2
	I _{DDAOPD}	VDDA+VDDO, CKPWRGD_PD# = 0		0.7	1	mA	1,2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.

² Input clock stopped.

³ In bypass mode, the PLL is off and IDDAO is ~50% of this value.



Electrical Characteristics-Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
PLL Bandwidth	BW	-3dB point in High BW Mode (100MHz)	2.2	3.6	4.8	MHz	1,5
PLL Bandwidth	DVV	-3dB point in Low BW Mode (100MHz)	High BW Mode (100MHz) 2.2 3.6 4.8 MHz Low BW Mode (100MHz) 1 1.6 2.5 MHz s band Gain (100MHz) 1.3 2.5 dB differentially, PLL Mode 45 50.2 55 % tially, Bypass Mode @100MHz -1 -0.5 0 % s Mode, V _T = 50% 3400 4300 5200 ps Mode V _T = 50% 0 50 150 ps V _T = 50% 37 50 ps PLL mode 24.1 50 ps	1,5			
PLL Jitter Peaking	t _{JPEAK}	Peak Pass band Gain (100MHz)		1.3	2.5	dB	1
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50.2	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz	-1	-0.5	0	%	1,3
Skew, Input to Output	t _{pdBYP}	Bypass Mode, V _T = 50%	3400	4300	5200	ps	1
Skew, input to Output	t _{pdPLL}	PLL Mode V _T = 50%	0	50	150	MHz MHz dB % ps ps ps ps	1,4
Skew, Output to Output	t _{sk3}	V _T = 50%		37	50	ps	1,4
Jitter, Cycle to cycle	+.	PLL mode		24.1	50	ps	1,2
Jitter, Cycle to Cycle	t _{jcyc-cyc}	Additive Jitter in Bypass Mode	entially, PLL Mode		ps	1,2	

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Phase Jitter Parameters

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
	t _{jphPCleG2} PCle Gen 1 30 58 86 ps (p-p) 1 PCle Gen 2 Lo Band 10kHz < f < 1.5MHz PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) PCle Gen 3 Common Clock Architecture (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz) t _{jphPCleG3} PCle Gen 3 Separate Reference No Spread (SRnS) (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz) t _{jphPCleG3} PCle Gen 3 Separate Reference No Spread (SRnS) (PLL BW of 2-4 or 2-5MHz, CDR = 10MHz) t _{jphPCleG3} PCle Gen 1 0.1 5 N/A ps (p-p) 1 PCle Gen 2 Lo Band 1.5MHz < f < 1.5MHz PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) PCle Gen 3 PCle Ge	1,2,3,5						
PARAMETER Phase Jitter, PLL Mode Additive Phase Jitter, Bypass Mode				0.9	1.4	3		1,2,3,5
Phase litter PLI Mode	¹ jphPCleG2	ü		2.1	2.6	3.1		1,2,3,5
T Hade ditter, T LE Widde	Total Part Tot	1,2,3,5						
	,,			0.5	0.6	0.7		1,2,3,5
	t _{iphPCleG1}	PCle Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
				0.1	0.5	N/A		1,2,3,4, 5
	^l jphPCleG2	-		0.1	0.3	N/A		1,2,3,4
, , , , , , , , , , , , , , , , , , , ,	t _{jphPCleG3}			0.2	0.3	N/A		1,2,3,4
bypass wode	t _{jph125M0}			200	300	N/A		1,6
	t _{jph125M1}			313	350	N/A		1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

⁴ All outputs at default slew rate

⁵ The MIN/TYP/MAX values of each BW setting track each other, i.e., Low BW MAX will never occur with Hi BW MIN.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

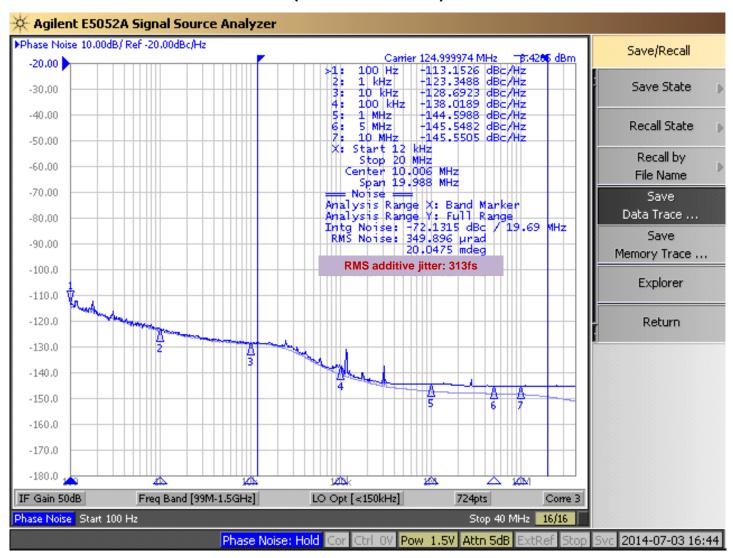
⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]

⁵ Driven by 9FGU0831 or equivalent

⁶ Rohde&Schartz SMA100



Additive Phase Jitter Plot: 125M (12kHz to 20MHz)





General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Bl	ock '	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		æ	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus Address is Latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte **N+X-1**
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ভ	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



SMBus Table: Output Enable Register ¹

Byte 0	Name	71.2		Default		
Bit 7	Reserved					
Bit 6	Reserved					
Bit 5	DIF OE1	DIF OE1 Output Enable RW Low/Low Enabled				
Bit 4	Reserved					
Bit 3	DIF OE0	Output Enable	RW	Low/Low	Enabled	1
Bit 2		Reserved				1
Bit 1	Reserved					1
Bit 0		Reserved				1

^{1.} A low on these bits will overide the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Control Function Type 0 1		Default	
Bit 7	PLLMODERB1	PLL Mode Readback Bit 1	R	See PLL Operating Mode Table		Latch
Bit 6	PLLMODERB0	PLL Mode Readback Bit 0	R	Gee i LL Operai	ing wode rable	Latch
Bit 5	PLLMODE_SWCNTRL	Enable SW control of PLL Mode	RW	Values in B1[7:6] Values in B1[4:3] set PLL Mode set PLL Mode		0
Bit 4	PLLMODE1	PLL Mode Control Bit 1	RW ¹	See PLL Operating Mode Table		0
Bit 3	PLLMODE0	PLL Mode Control Bit 0	RW ¹	See FLL Operat	ing wode rable	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.55V	01 = 0.65V	1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10= 0.75V	11 = 0.85V	0

^{1.} B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	71.		Default			
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	SLEWRATESEL DIF1 Slew Rate Selection RW Slow Setting Fast Setting				1		
Bit 4	Reserved						
Bit 3	SLEWRATESEL DIF0	Slew Rate Selection	RW	Slow Setting	Fast Setting	1	
Bit 2		Reserved				1	
Bit 1	Reserved						
Bit 0		Reserved				1	

SMBus Table: FB Slew Rate Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				1
Bit 6		Reserved				1
Bit 5		Reserved				
Bit 4		Reserved				0
Bit 3		Reserved				0
Bit 2		Reserved				1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL FB	Adjust Slew Rate of FB	RW	Slow Setting	Fast Setting	1

Byte 4 is Reserved and reads back 'hFF



SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R		0	
Bit 6	RID2	Revision ID	R	A rev = 0000		0
Bit 5	RID1	Revision ID	R	A lev -	0	
Bit 4	RID0		R		0	
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001	- IDT	0
Bit 1	VID1	VENDOR ID	R	0001 = IDT		0
Bit 0	VID0		R		1	

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Doving Type	R	00 = FGx, 01 =	0	
Bit 6	Device Type0	- Device Type	R	10 = DMx, 1	1	
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R		0	
Bit 3	Device ID3	Device ID	R	000100 hina	ny or 02 hay	0
Bit 2	Device ID2	Device iD	R	000100 billa	000100 binary or 02 hex	
Bit 1	Device ID1		R			1
Bit 0	Device ID0]	R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default
Bit 7	Reserved					
Bit 6	Reserved					
Bit 5	Reserved					
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	er will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0



Marking Diagrams





Notes:

- 1. "LOT" is the lot sequence number.
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3. Line 2: truncated part number
- 4. "L" denotes RoHS compliant package.
- 5. "I" denotes industrial temperature range device.

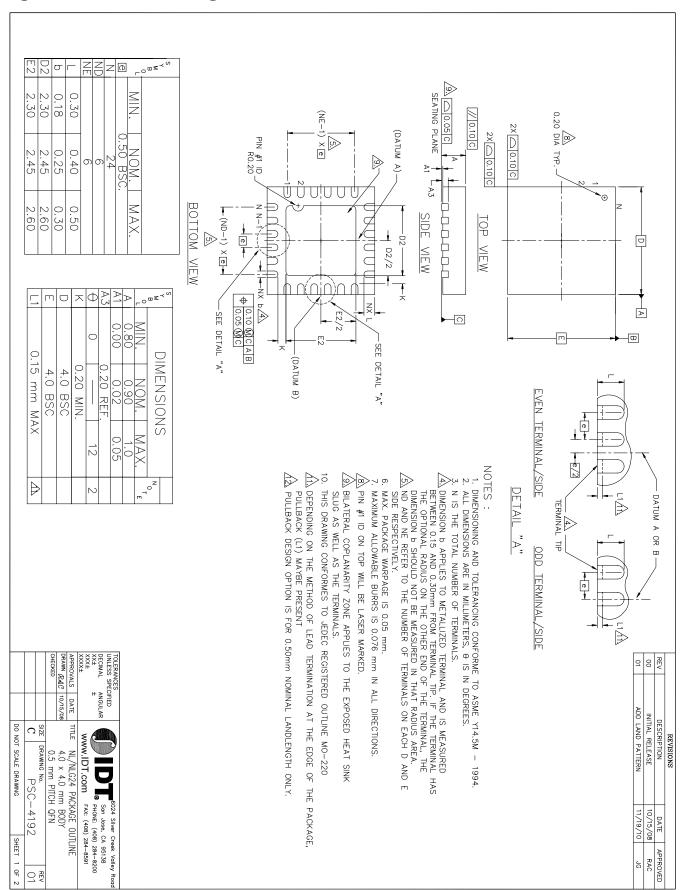
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	Θ _{JC}	Junction to Case		62	°C/W	1
	Θ_{Jb}	Junction to Base	5.4		°C/W	1
Thermal Resistance	Θ_{JA0}	Junction to Air, still air	NLG20 50	°C/W	1	
Theimai nesistance	Θ_{JA1}	Junction to Air, 1 m/s air flow	NLG24	43	°C/W	1
	Θ_{JA3}	Junction to Air, 3 m/s air flow	39		°C/W	1
	Θ_{JA5}	Junction to Air, 5 m/s air flow	w 38	°C/W	1	

¹ePad soldered to board

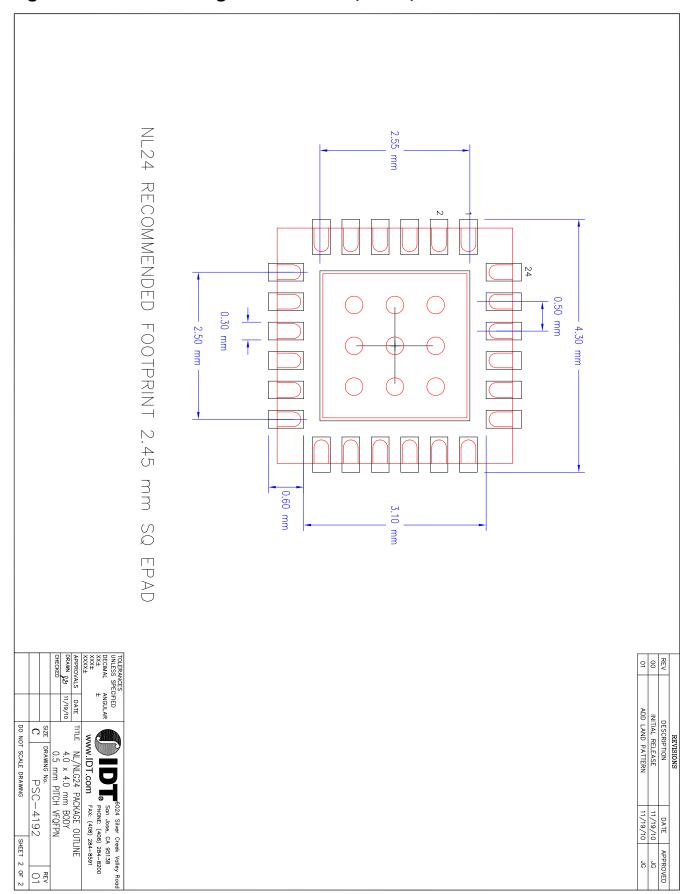


Package Outline and Package Dimensions (NLG24)





Package Outline and Package Dimensions (NLG24), cont.





Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBU0231AKLF	Tubes	24-pin VFQFPN	0 to +70° C
9DBU0231AKLFT	Tape and Reel	24-pin VFQFPN	0 to +70° C
9DBU0231AKILF	Tubes	24-pin VFQFPN	-40 to +85° C
9DBU0231AKILFT	Tape and Reel	24-pin VFQFPN	-40 to +85° C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History

Rev.	Initiator	Issue Date	Description	Page #	
A RDW			Updated electrical tables with char data.		
	7/14/2014	2. Added an additive phase jitter plot.	Various		
	אטח	7/14/2014	3. Added 12kHz to 20MHz additive phase jitter spec.	various	
		4. Updated Amplitude control bit descriptions in Byte 1.			
B RDW	9/19/2014	Updated SMBus Input High/Low parameters conditions, MAX values,	6		
		and footnotes.			
C RDW			Updated pin out and pin descriptions to show ePad on package		
	4/3/2015	connected to ground.	1-4		
	אטח	4/3/2013	2. Updated front page text to standard format for these devices. Added	1-4	
			explicit bullet indicated Spread Spectrum compatibility.		
D RDW		RDW 4/22/2014	Updated Clock Input Parameters table to be consistent with PCIe		
	DDW		Vswing parameter.	1,5	
	ווטעע		2. Minor updates to front page text for family consistency.	1,5	
			3. Add note about epad to Power Connections table.		

[&]quot;A" is the device revision designator (will not correlate with the datasheet revision).



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